## Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted.

| Symbol | Parameter | Value | Units |
| :---: | :--- | :---: | :---: |
| $\mathrm{P}_{\mathrm{D}}$ | Power Dissipation @ $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ | 1.0 | W |
|  | Power Dissipation @ $\mathrm{T}_{\mathrm{L}}=25^{\circ} \mathrm{C}$ at 4 mm distance from the glass <br> package | 1.3 |  |
|  | Derate above $50^{\circ} \mathrm{C}$ | 6.67 | ${ }^{\circ} \mathrm{C}$ |
|  | Operating and Storage Temperature Range | $-65+200$ |  |

## Electrical Characteristics

Values are at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted.

| Device | Zener Voltage ${ }^{(1)}$ |  |  | Zener Impedance |  |  | Leakage Current |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | $\mathrm{V}_{\mathrm{Z}}$ (V) |  | $\mathrm{I}_{\mathrm{Z}}$ | $\frac{\mathrm{Z}_{\mathrm{Z}} @ \mathrm{I}_{\mathrm{Z}}}{(\Omega)}$ | $\mathrm{Z}_{\mathrm{ZK}}$ @ $\mathrm{I}_{\mathrm{ZK}}$ |  | $\mathrm{I}_{\mathrm{R}} @ \mathrm{~V}_{\mathrm{R}}$ |  |
|  | Min. | Max. | mA |  | ( $\Omega$ ) | (mA) | $\mu \mathrm{A}$ Max. | Volts |
| BZX85C3V3 | 3.1 | 3.5 | 80 | 20 | 400 | 1 | 60 | 1 |
| BZX85C3V6 | 3.4 | 3.8 | 60 | 15 | 500 | 1 | 30 | 1 |
| BZX85C3V9 | 3.7 | 4.1 | 60 | 15 | 500 | 1 | 5 | 1 |
| BZX85C4V3 | 4.0 | 4.6 | 50 | 13 | 500 | 1 | 3 | 1 |
| BZX85C4V7 | 4.4 | 5 | 45 | 13 | 600 | 1 | 3 | 1.5 |
| BZX85C5V1 | 4.8 | 5.4 | 45 | 10 | 500 | 1 | 1 | 2 |
| BZX85C5V6 | 5.2 | 6 | 45 | 7 | 400 | 1 | 1 | 2 |
| BZX85C6V2 | 5.8 | 6.6 | 35 | 4 | 300 | 1 | 1 | 3 |
| BZX85C6V8 | 6.4 | 7.2 | 35 | 3.5 | 300 | 1 | 1 | 4 |
| BZX85C7V5 | 7.0 | 7.9 | 35 | 3 | 200 | 0.5 | 1 | 4.5 |
| BZX85C8V2 | 7.7 | 8.7 | 25 | 5 | 200 | 0.5 | 1 | 5 |
| BZX85C9V1 | 8.5 | 9.6 | 25 | 5 | 200 | 0.5 | 1 | 6.5 |
| BZX85C10 | 9.4 | 10.6 | 25 | 7 | 200 | 0.5 | 0.5 | 7 |
| BZX85C11 | 10.4 | 11.6 | 20 | 8 | 300 | 0.5 | 0.5 | 7.7 |
| BZX85C12 | 11.4 | 12.7 | 20 | 9 | 350 | 0.5 | 0.5 | 8.4 |
| BZX85C13 | 12.4 | 14.1 | 20 | 10 | 400 | 0.5 | 0.5 | 9.1 |
| BZX85C15 | 13.8 | 15.6 | 15 | 15 | 500 | 0.5 | 0.5 | 10.5 |
| BZX85C16 | 15.3 | 17.1 | 15 | 15 | 500 | 0.5 | 0.5 | 11 |
| BZX85C18 | 16.8 | 19.1 | 15 | 20 | 500 | 0.5 | 0.5 | 12.5 |
| BZX85C20 | 18.8 | 21.2 | 10 | 24 | 600 | 0.5 | 0.5 | 14 |
| BZX85C22 | 20.8 | 23.3 | 10 | 25 | 600 | 0.5 | 0.5 | 15.5 |
| BZX85C24 | 22.8 | 25.6 | 10 | 25 | 600 | 0.5 | 0.5 | 17 |
| BZX85C27 | 25.1 | 28.9 | 8 | 30 | 750 | 0.25 | 0.5 | 19 |
| BZX85C30 | 28 | 32 | 8 | 30 | 1000 | 0.25 | 0.5 | 21 |
| BZX85C33 | 31 | 35 | 8 | 35 | 1000 | 0.25 | 0.5 | 23 |
| BZX85C36 | 34 | 38 | 8 | 40 | 1000 | 0.25 | 0.5 | 25 |
| BZX85C39 | 37 | 41 | 6 | 45 | 1000 | 0.25 | 0.5 | 27 |
| BZX85C43 | 40 | 46 | 6 | 50 | 1000 | 0.25 | 0.5 | 30 |
| BZX85C47 | 44 | 50 | 4 | 90 | 1500 | 0.25 | 0.5 | 33 |
| BZX85C51 | 48 | 54 | 4 | 115 | 1500 | 0.25 | 0.5 | 36 |
| BZX85C56 | 52 | 60 | 4 | 120 | 2000 | 0.25 | 0.5 | 39 |
| $\mathrm{V}_{\mathrm{F}}$ Forward Voltage = 1.2 V Max @ $\mathrm{I}_{\mathrm{F}}=200 \mathrm{~mA}$ |  |  |  |  |  |  |  |  |

$\mathrm{V}_{\mathrm{F}}$ Forward Voltage =1.2 V Max @ $\mathrm{I}_{\mathrm{F}}=200 \mathrm{~mA}$
Note:

1. Zener Voltage $\left(\mathrm{V}_{\mathrm{Z}}\right)$ : The zener voltage is measured with the device junction in the thermal equilibrium at the lead temperature $\left(\mathrm{T}_{\mathrm{L}}\right)$ at $30^{\circ} \mathrm{C} \pm 1^{\circ} \mathrm{C}$ and $3 / 8^{\prime \prime}$ lead length.

## Top Mark Information

| Device | Line 1 | Line 2 | Line 3 | Line 4 | Line 5 |
| :---: | :---: | :---: | :---: | :---: | :---: |
| BZX85C3V3 | LOGO | 85C | 3V3 |  | XY |
| BZX85C3V6 | LOGO | 85C | 3V6 |  | XY |
| BZX85C3V9 | LOGO | 85C | 3V9 |  | XY |
| BZX85C4V3 | LOGO | 85C | 4V3 |  | XY |
| BZX85C4V7 | LOGO | 85C | 4V7 |  | XY |
| BZX85C5V1 | LOGO | 85C | 5V1 |  | XY |
| BZX85C5V6 | LOGO | 85C | 5V6 |  | XY |
| BZX85C6V2 | LOGO | 85C | 6V2 |  | XY |
| BZX85C6V8 | LOGO | 85C | 6V8 |  | XY |
| BZX85C7V5 | LOGO | 85C | 7V5 |  | XY |
| BZX85C8V2 | LOGO | 85C | 8V2 |  | XY |
| BZX85C9V1 | LOGO | 85C | 9 V 1 |  | XY |
| BZX85C10 | LOGO | 85C | 10 |  | XY |
| BZX85C11 | LOGO | 85C | 11 |  | XY |
| BZX85C12 | LOGO | 85C | 12 |  | XY |
| BZX85C13 | LOGO | 85C | 13 |  | XY |
| BZX85C15 | LOGO | 85C | 15 |  | XY |
| BZX85C16 | LOGO | 85C | 16 |  | XY |
| BZX85C18 | LOGO | 85C | 18 |  | XY |
| BZX85C20 | LOGO | 85C | 20 |  | XY |
| BZX85C22 | LOGO | 85C | 22 |  | XY |
| BZX85C24 | LOGO | 85C | 24 |  | XY |
| BZX85C27 | LOGO | 85C | 27 |  | XY |
| BZX85C30 | LOGO | 85C | 30 |  | XY |
| BZX85C33 | LOGO | 85C | 33 |  | XY |
| BZX85C36 | LOGO | 85C | 36 |  | XY |
| BZX85C39 | LOGO | 85C | 39 |  | XY |
| BZX85C43 | LOGO | 85C | 43 |  | XY |
| BZX85C47 | LOGO | 85C | 47 |  | XY |
| BZX85C51 | LOGO | 85C | 51 |  | XY |
| BZX85C56 | LOGO | 85C | 56 |  | XY |

## Top Mark Information (Continued)



$$
\begin{aligned}
& 1^{\text {st }} \text { line: ON - ON Semiconductor Logo } \\
& 2^{\text {nd }} \text { line: Device Name }-3^{\text {rd }} \text { to } 4^{\text {th }} \text { characters of device name for } 1 N x x \text { series } \\
& \text { or } 4^{\text {th }} \text { to } 6^{\text {th }} \text { characters for BZXyy series } \\
& \begin{array}{l}
3^{\text {rd }} \text { line: Device Name }-5^{\text {th }} \text { to } 6^{\text {th }} \text { characters of device name for } 1 N x x \text { series } \\
\text { or Voltage rating for BZXyy series }
\end{array} \\
& \text { or Voltage rating for BZXyy series } \\
& 4^{\text {th }} \text { line: Device Name }-7^{\text {th }} \text { to } 8^{\text {th }} \text { characters of device name for } 1 N x x \text { series } \\
& \text { or Large Die identification only for BZXyy series } \\
& 5^{\text {th }} \text { line: Date Code - Two Digit - Six Weeks Date Code }
\end{aligned}
$$

## General Requirements:

### 1.0 Cathode Band

2.0 First Line:(ON)- ON Semiconductor Logo
3.0 Second Line: Device name - For $1 N x x$ series: $3^{\text {rd }}$ to $4^{\text {th }}$ characters of the device name. For BZxx series: $4^{\text {th }}$ to $6^{\text {th }}$ characters of the device name.
4.0 Third Line: Device name - For $1 N x x$ series: $5^{\text {th }}$ to $6^{\text {th }}$ characters of the device name.

For BZXyy series: Voltage rating
5.0 Third Line: Device name - For 1 Nxx series: $7^{\text {th }}$ to $8^{\text {th }}$ characters of the device name.
(the 8th character is the large die identification)
For BZXyy series: Large Die Identification character
6.0 Fourth Line: Date Code - Two Digit - Six Weeks Date Code Where: X represents the last digit of the calendar year Y represents the Six weeks numeric code 7.0 Devices shall be marked as required in the device specification (PID or OSPI Test Spec).
8.0 Maximum no. of marking lines: 5
9.0 Maximum no. of digits per line: 3
10.0 OSPI logo must be $20 \%$ taller than the alphanumeric marking and should occupy the 2 characters of the specified line.
11.0 Marking Font: Arial (Except OSPI Logo)
12.0 First character of each marking line must be aligned vertically
13.0 All device markings must be based on ON Semiconductor device specification.

## Physical Dimensions

## DO-204AL (DO-41)



NOTES: UNLESS OTHERWISE SPECIFIED
A) PACKAGE STANDARD REFERENCE

JEDEC DO-204 VARIATION AL.
B) PACKAGE BODY CAN BE PLASTIC OR HERMETICALLY SEALED GLASS
D) ALL DIMENSIONS ARE IN MILLIMETERS
E) DRAWING FILE NAME: D041AREV2

Figure 7. AXIAL LEADED, GLASS, JEDEC DO204, VARIATION AL
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037318A 037352H 039573E 041950FB 042158E 045158A 053400BM 054279X 055160CM 056201A 056203H 056258X 056726R 056731D 058285F 059858C 061219G 061253C 061258D 062330D 062876B 062878R

